
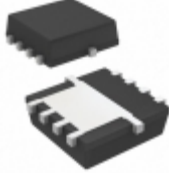
	<h2>SI7812DN-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SI7812DN-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 75V 16A 1212-8 PPAK</p> <p>Datenblätter:  SI7812DN-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 162215 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI7812DN-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 75V 16A 1212-8 PPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	162215 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	PowerPAK® 1212-8
Supplier Device-Gehäuse	PowerPAK® 1212-8
Verlustleistung (max)	3.8W (Ta), 52W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	75V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	16A (Tc)
Rds On (Max) @ Id, Vgs	37 mOhm @ 7.2A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	24nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	840pF @ 35V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)













































SI7812DN-T1-GE3 ist neu im Original, Suche SI7812DN-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7812DN-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI7812DN-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI7812DN-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 75V 16A 1212-8</p>	 <p>SI7818DN SI SI7818DN SI</p>	 <p>SI7818DN-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 150V 2.2A 1212-8</p>	 <p>SI7818DN-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 150V 2.2A 1212-8</p>
 <p>SI7812DN SI SI7812DN SI</p>	 <p>SI7811DN SI SI7811DN SI</p>	 <p>SI7818DN-T1-GE3 Vishay / Siliconix MOSFET N-CH 150V 2.2A 1212-8</p>	 <p>SI7812DN-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 75V 16A 1212-8 PPAK</p>

heiße Teile

Mehr

 SI7794DP-T1-GE3	 SI7794DP-T1-GE3	 SI7798DP-T1-GE3	D SI7804DN	 SI7804DN-T1-E3
 SI7804DN-T1-E3	 SI7806ADN	D SI7806ADN-T1-E3	 SI7806ADN-T1-E3	 SI7806ADN-T1-E3-PBF
 SI7806ADN-T1-GE3	 SI7806ADN-T1-GE3	 SI7806AEDN-T1-E3	 SI7806BDN	 SI7806BDN-T1-GE3
D SI7806DN-T1-E3	 SI7806DN-T1-GE3	 SI7810DN	 SI7810DN-T1	 SI7810DN-T1-E
 SI7810DN-T1-E3	 SI7810DN-T1-E3	 SI7812DN-T1-E3	 SI7812DN-T1-E3	 SI7812DN-T1-GE3
 SI7818DN-T1-E3	 SI7818DN-T1-E3	D SI7820DN-T1-E3	 SI7820DN-T1-E3	 SI7820DN-T1-GE3
 SI7820DN-T1-GE3	D SI7840BDP	 SI7840BDP-T1-E3	 SI7840BDP-T1-E3	 SI7840BDP-T1-GE3
 SI7840BDP-T1-GE3	 SI7840DP	 SI7840DP-T1	 SI7840DP-T1-E3	 SI7840DP-T1-GE3
 SI7840DP-T1-GE3	 SI7842DP	 SI7842DP-T1-E3	D SI7842DP-T1-E3	 SI7842DP-T1-GE3
 SI7842DP-T1-GE3	 SI7844DP	 SI7844DP-T1	 SI7844DP-T1-E3	 SI7844DP-T1-E3

Contact us:Info@Y-IC.com

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